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**U.S. PATENT DOCUMENTS**

Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date (if appropriate)
<i>[initials]</i>	5,612,250	03/18/1997	Ohtani et al.			
<i>[initials]</i>	5,543,352	08/06/1996	Ohtani et al.			
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<i>[initials]</i>	Specification and Drawings for Patent Application Serial No. 09/610,637, "Laser Irradiation Apparatus, Laser Irradiation Method, Semiconductor Device, and Method of Manufacturing a Semiconductor Device".
<i>[initials]</i>	Y. Helen et al. "Reproducible High Field Effect Mobility Polysilicon Thin Film Transistors Involving Pulsed Nd:YVO ₄ Laser Crystallization" IEEE IDM 99, p. 297.
Examiner	Date Considered 12/11/01

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